

# HSD276A

# Silicon Schottky Barrier Diode for Detector

REJ03G0604-0100

(Previous: ADE-208-1385)

Rev.1.00 Apr 15, 2005

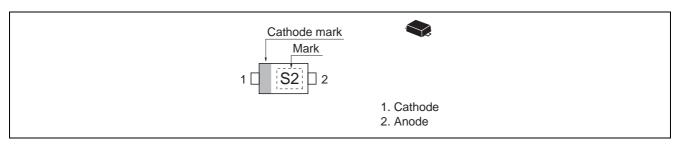
### **Features**

- High forward current, Low capacitance.
- Super small Flat Lead Package (SFP) is suitable for surface mount design.

# **Ordering Information**

Type No.	Laser Mark	Package Name	Package Code (Previous Code)
HSD276A	S2	SFP	PUSF0002ZB-A
			(SFP)

## **Pin Arrangement**



# **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Value	Unit
Repetitive peak reverse voltage	$V_{RRM}$	5	V
Reverse voltage	V <sub>R</sub>	3	V
Average rectified current	Io	30	mA
Junction temperature	Tj	125	°C
Storage temperature	Tstg	−55 to +125	°C

## **Electrical Characteristics**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse voltage	$V_R$	3.0	_	_	V	I <sub>R</sub> = 1 mA
Reverse current	I <sub>R</sub>	_	_	50	μА	V <sub>R</sub> = 0.5 V
Forward current	I <sub>F</sub>	35	_	_	mA	V <sub>F</sub> = 0.5 V
Capacitance	С		_	0.85	pF	V <sub>R</sub> = 0.5 V, f = 1 MHz
ESD-Capability *1	_	30	_	_	V	C = 200 pF, R = 0 $\Omega$ , Both forward and
						reverse direction 1 pulse.

Notes: 1. Failure criterion ;  $I_R > 100 \mu A$  at  $V_R = 0.5 V$ 

2. Please do not use the soldering iron due to avoid high stress to the SFP package.

## **Main Characteristic**

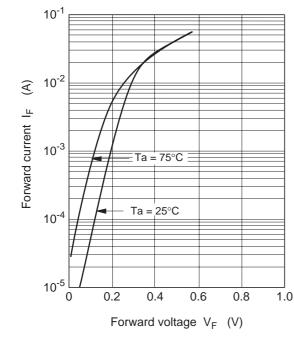


Fig.1 Forward current vs. Forward voltage

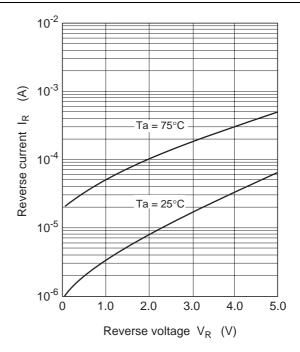
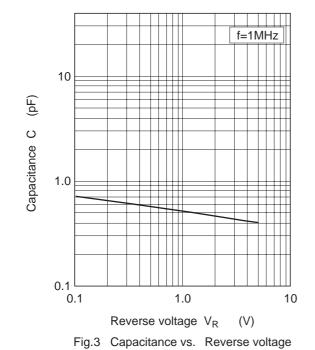
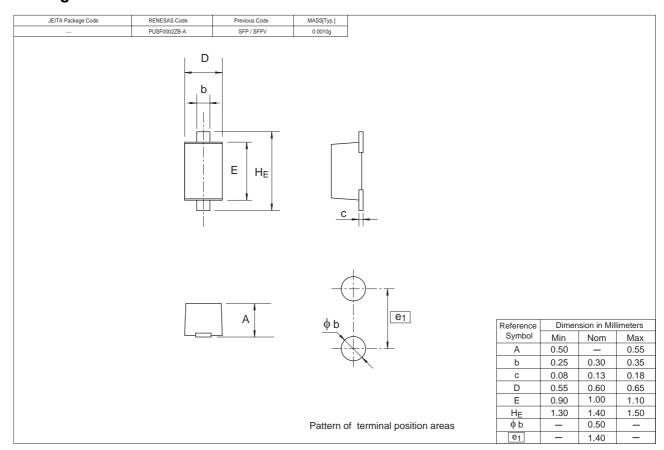


Fig.2 Reverse current vs. Reverse voltage



# **Package Dimensions**



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